

# UNISONIC TECHNOLOGIES CO., LTD

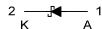
MBR0540 DIODE

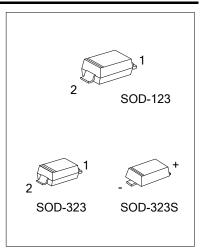
# **SCHOTTKY RECTIFIER**

#### **■ FEATURES**

- \* For surface mounted applications
- \* Low forward voltage drop (V<sub>F</sub>=0.50V Typ. at 0.5A)
- \* Guard ring for transient and ESD protection



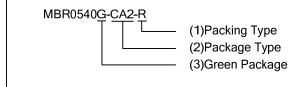




#### **■ ORDERING INFORMATION**

Order Number		Daakana	Pin Assignment		De akin n	
Lead Free	Halogen Free	Package	1	2	Packing	
MBR0540L-CA2-R	MBR0540G-CA2-R	SOD-123	Α	K	Tape Reel	
MBR0540L-CB2-R	MBR0540G-CB2-R	SOD-323	Α	K	Tape Reel	
MBR0540L-CB2S-R	MBR0540G-CB2S-R	SOD-323S	Α	K	Tape Reel	

Note: Pin assignment: A: Anode K: Cathode



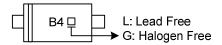
(1) R: Tape Reel

(2) CA2: SOD-123, CB2: SOD-323,

CB2S: SOD-323S

(3) G: Halogen Free and Lead Free, L: Lead Free

#### **■** MARKING



MBR0540 DIODE

## ■ ABSOLUTE MAXIMUM RATINGS (Single Diode @T<sub>A</sub>=25°C, unless otherwise specified)

PARAMETER		SYMBOL	RATINGS	UNIT
Maximum Repetitive Peak Reverse Voltage		$V_{RRM}$	40	V
Maximum DC Blocking Voltage		V <sub>R</sub>	40	V
Working Peak Reverse Voltage		$V_{RWM}$	40	V
Maximum RMS Reverse Voltage		V <sub>R(RMS)</sub>	28	V
Maximum Voltage Rate of Change (Rated V <sub>R</sub> )		dv/dt	1000	V/µs
Average Rectified Forward Current		l <sub>out</sub>	500	mA
Non-Repetitive Peak Forward Surge Current		I <sub>FSM</sub>	5.5	Α
	SOD-123	P <sub>D</sub>	410	mW
Power Dissipation	SOD-323 SOD-323S		200	mW
Junction Temperature		TJ	+150	°C
Storage Temperature		T <sub>STG</sub>	-65 ~ +150	°C

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

#### **■ THERMAL DATA**

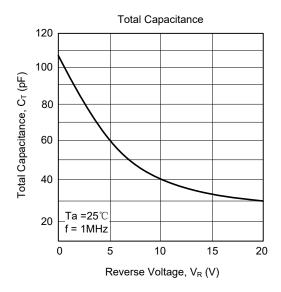
PARAMETER		SYMBOL	RATINGS	UNIT
	SOD-123		244	°C/W
Junction to Ambient	SOD-323 SOD-323S	θја	500	°C/W

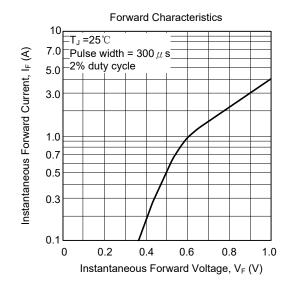
## ■ ELECTRICAL CHARACTERISTICS (T<sub>A</sub>=25°C, unless otherwise specified)

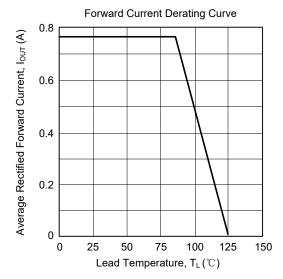
PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Reverse Breakdown Voltage	BV <sub>R</sub>	I <sub>R</sub> =20µA	40			V
Farmend Valle no Duon	$V_{F1}$	I <sub>F</sub> =0.5A			0.51	V
Forward Voltage Drop	V <sub>F2</sub>	I <sub>F</sub> =1A			0.62	V
Devene Laskana Cumant	$I_{R1}$	V <sub>R</sub> =20V			10	μΑ
Reverse Leakage Current	I <sub>R2</sub>	V <sub>R</sub> =40V			20	μΑ
Total Capacitance	Ст	V <sub>R</sub> =1V, f=1MHz			170	рF
Timical Dayana Dagayani Tina	l too	$I_F=I_R=10$ mA, $R_L=100$ Ω			4	ns
Typical Reverse Recovery Time		recover to 0.1 x I <sub>R</sub>				

MBR0540 DIODE

#### **■ TYPICAL CHARACTERISTICS**







UTC assumes no responsibility for equipment failures that result from using products at values that exceed, even momentarily, rated values (such as maximum ratings, operating condition ranges, or other parameters) listed in products specifications of any and all UTC products described or contained herein. UTC products are not designed for use in life support appliances, devices or systems where malfunction of these products can be reasonably expected to result in personal injury. Reproduction in whole or in part is prohibited without the prior written consent of the copyright owner. UTC reserves the right to make changes to information published in this document, including without limitation specifications and product descriptions, at any time and without notice. This document supersedes and replaces all information supplied prior to the publication hereof.